

Technical Data Sheet Opto Interrupter EAITRDA6

Features

- Fast response time
- High analytic
- High sensitivity
- Cut-off visible wavelength $\lambda_P=940\text{nm}$
- Pb Free
- This product itself will remain within RoHS compliant version.



Description

The **EAITRDA6** consists of an infrared emitting diode and an NPN silicon phototransistor, encased oblique angle (45°) on converging optical axis in a black Thermo-plastic housing. The phototransistor receives radiation from the IRED only, and avoids the noise from ambient light.

Applications

- Copier
- Scanner
- Non-contact Switching
- For Direct PC Board

Device Selection Guide

Device No.	Chip Material	LENS COLOR
IR	GaAlAs	Blue
PT	Silicon	Black

Absolute Maximum Ratings (Ta=25°C)

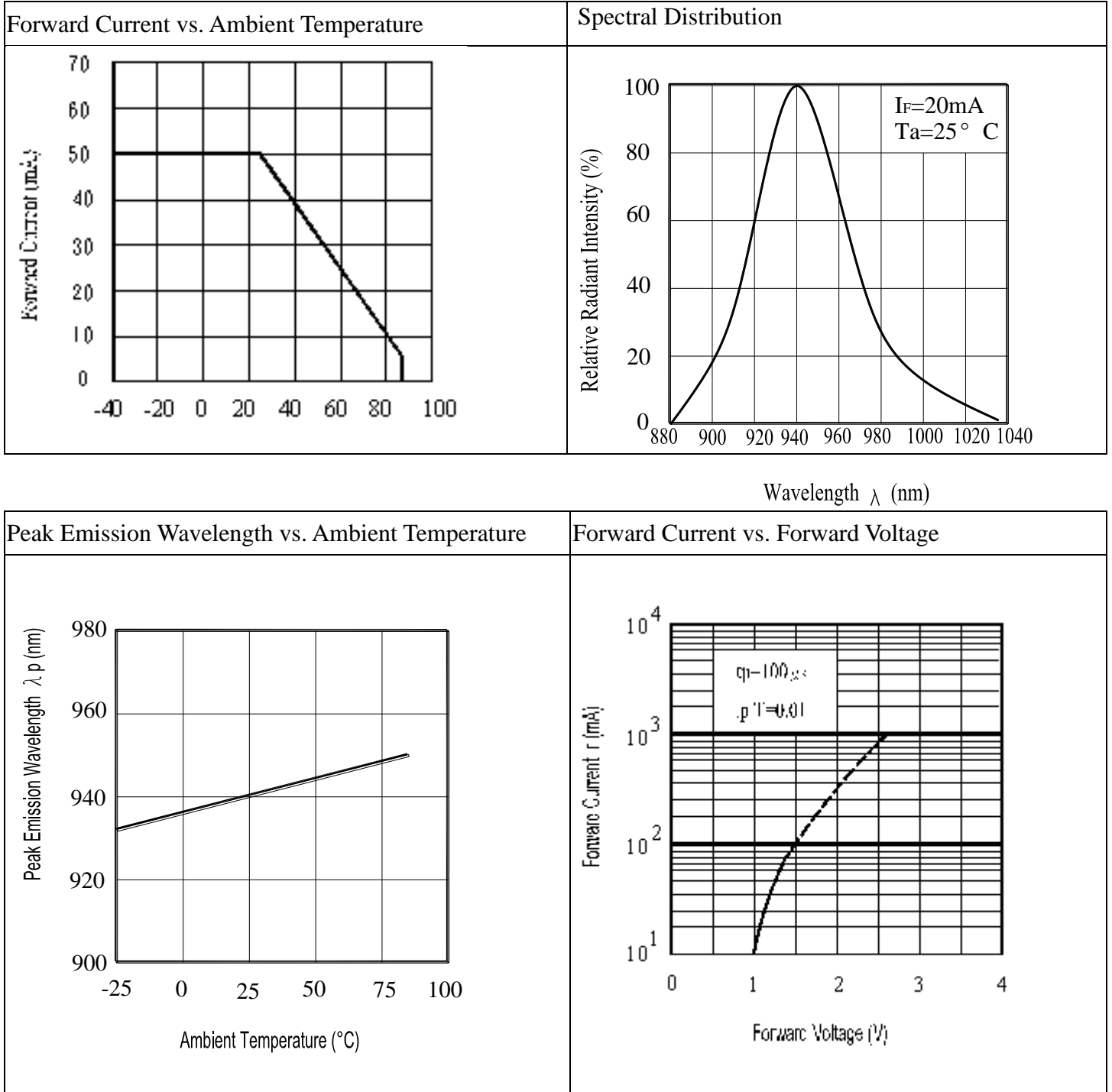
Parameter		Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	I _F	50	mA
	Peak Forward Current (*1) Pulse width ≤100μs, Duty cycle=1%	I _{FP}	1	A
Output	Collector Power Dissipation	P _C	75	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating Temperature		T _{opr}	-25~+85	°C
Storage Temperature		T _{stg}	-40~+85	°C
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		T _{sol}	260	°C

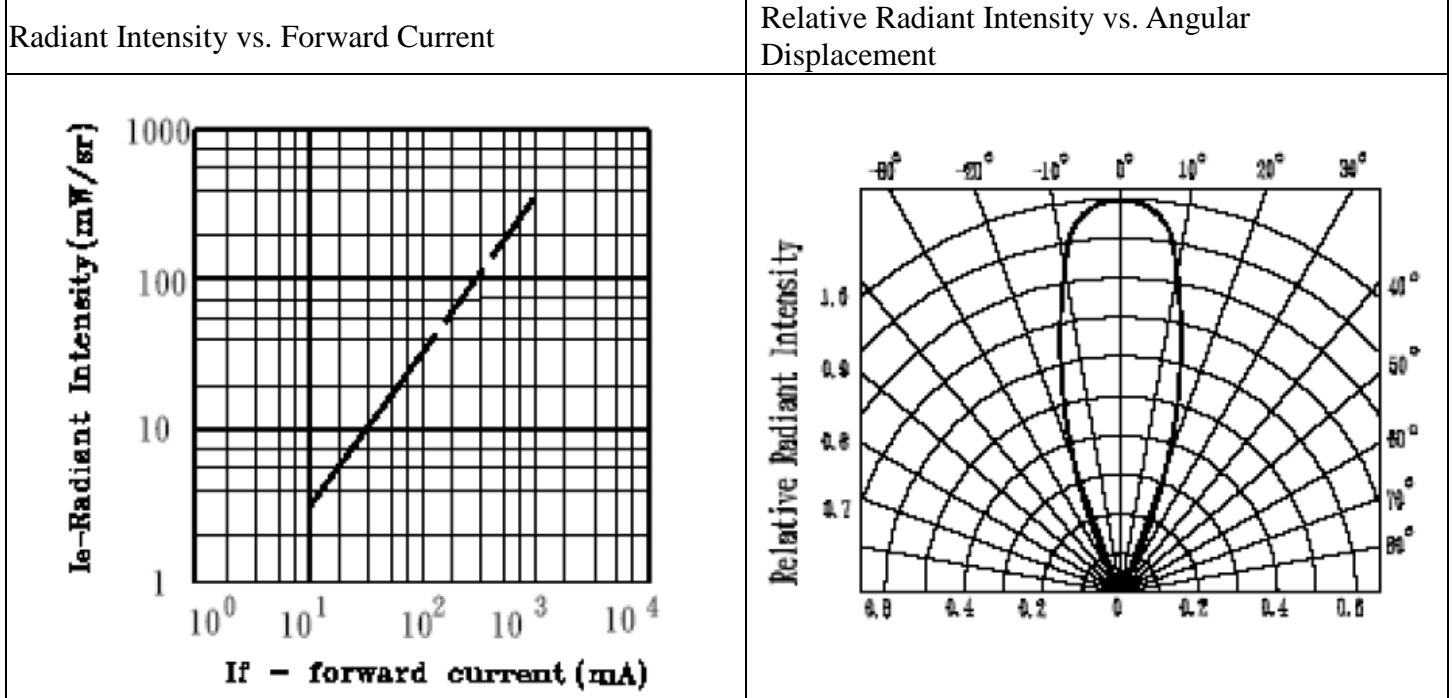
Notes: (*1) $t_w=100 \mu\text{sec.}$, $T=10 \text{ msec.}$ (*2) $t=5 \text{ Sec}$

Electro-Optical Characteristics (Ta=25°C)

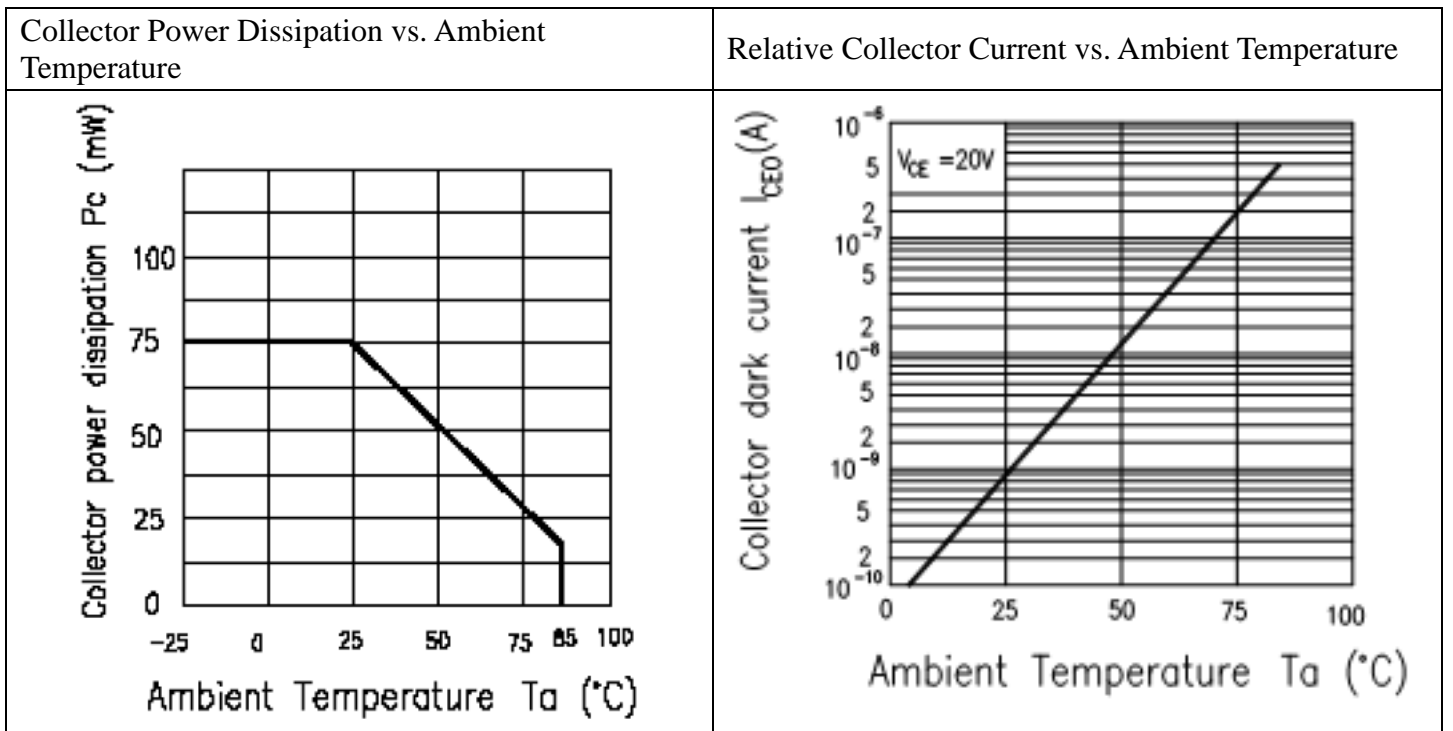
Parameter		Symbol	Min.	Typ.	Max.	Unit	Condition
Input	Forward Voltage	V _{F1}	-	1.2	1.5	V	I _F =20mA
		V _{F2}	-	1.4	1.85		I _F =100mA
		V _{F3}	-	2.6	4.0		I _F =1A
	Reverse Current	I _R	-	-	10	μA	V _R =5V
	Peak Wavelength	λ _P	-	940	-	nm	I _F =20mA
Output	Dark Current	I _{CEO}	-	-	100	nA	V _{CE} =20V, E _e =0mW/cm ²
	C-E Saturation Voltage	V _{CE(sat)}	-	-	0.4	V	I _C =2mA, E _e =1mW/cm
Collector Current(* 3)		I _{C(ON)A}	100	-	300	μ A	V _{CE} =5V, I _F =20mA
		I _{C(ON)B}	200	-	600	μ A	
		I _{C(ON)C}	400	-	1200	μ A	
Response Time	Rise Time	t _R	-	15	-	μs	V _{CE} =5V, I _C =1mA, R _L =1KΩ
	Fall Time	t _F	-	15	-	μs	

Typical Electrical/Optical/Characteristics Curves for IR

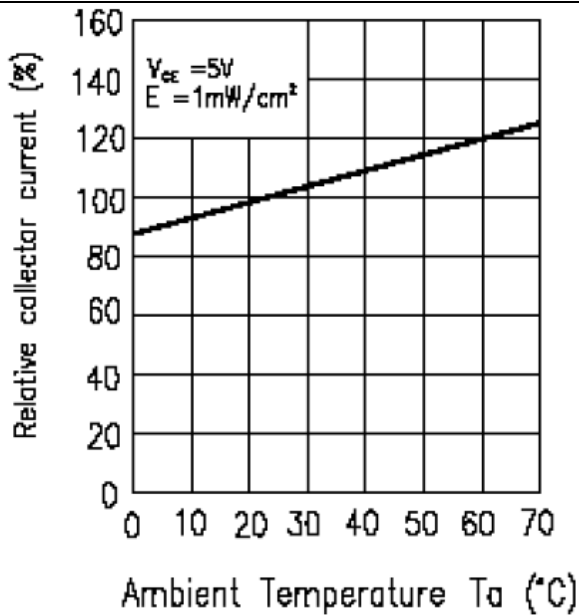




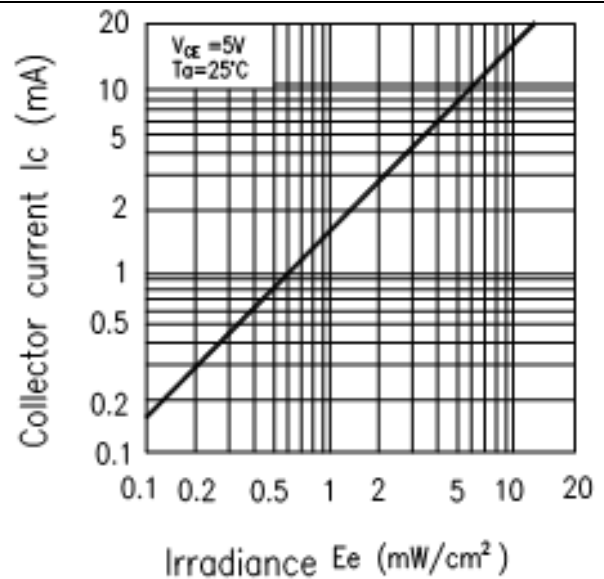
Typical Electro/Optical/Characteristics Curves for PT



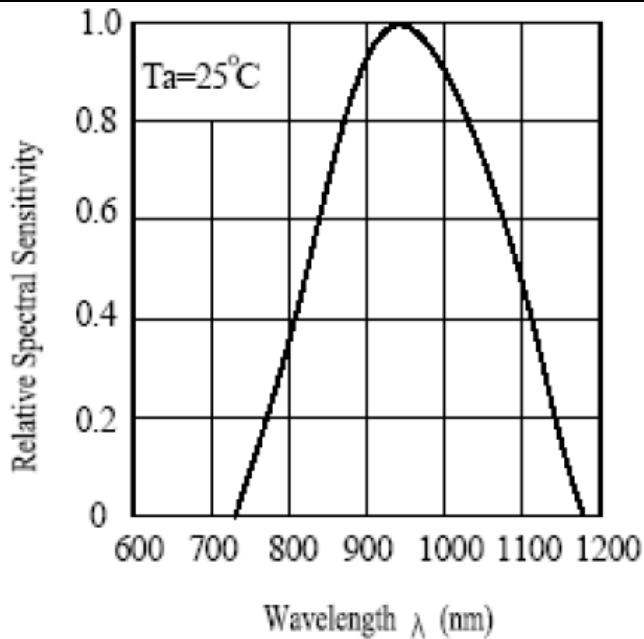
Relative collector current vs. Ambient Temperature



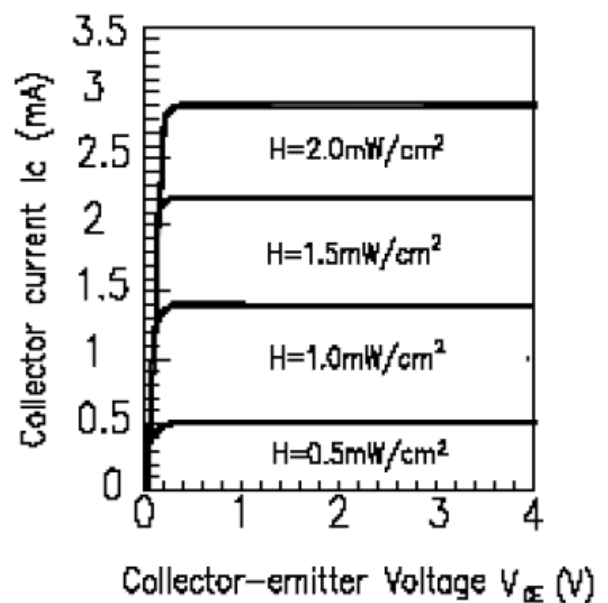
Collector Current vs. Irradiance



Relative Sensitivity vs. Wavelength



Collector current vs. Collector-Emitter Voltage



Reliability Test Item And Condition

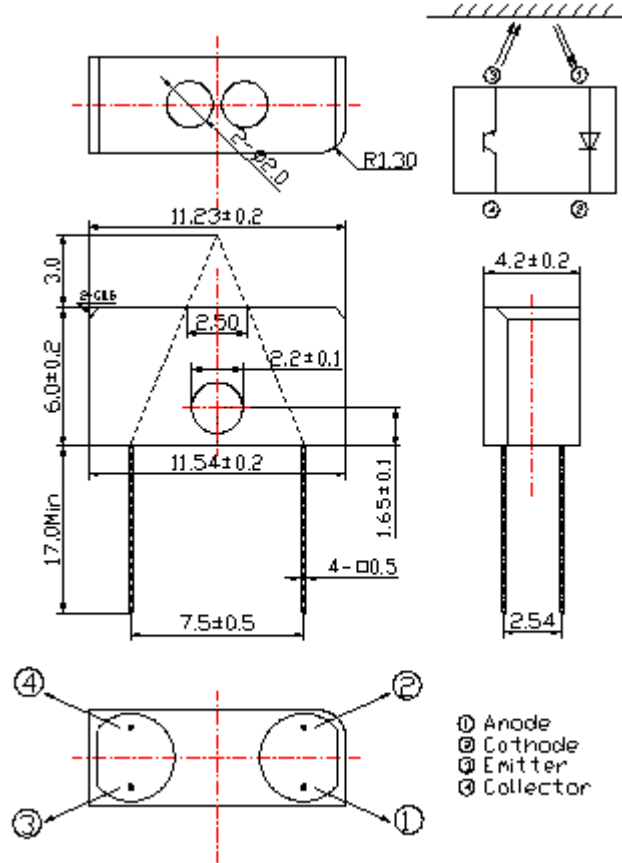
The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Condition	Test Hours/ Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	10 sec	22 PCs	Ic(on) ≤ L×0.8 L :Lower specification limit	0/1
2	Temperature Cycle	H : +100°C 15 mins ↑ 5 min ↓ L : -40°C 15 min	300 cycle	22 PCs		0/1
3	Thermal Shock	H : +100°C 5 min ↑ 10 sec ↓ L : -10°C 5 min	300 cycle	22 PCs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 PCs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000 hrs	22 PCs		0/1
6	DC Operating Life	V _{CE} =5V I _F =20mA	1000 hrs	22 PCs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 PCs		0/1

Package Dimension



Notes:

1. All dimensions are in millimeters
2. Tolerances unless dimensions ± 0.2 mm
3. Lead spacing is measured where the lead emerge from the package
4. Above specification may be changed without notice. EVERLIGHT Americas will reserve authority on material change for above specification
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